

HPA Series

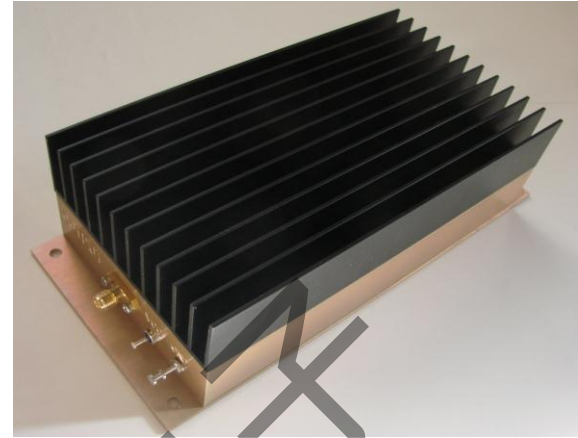
760-880MHz 16-20W RF Power Amplifier

Features

- Frequency Range: 760-880MHz (min)
- Gain: 39.5dB (typ.)
- P_{3dB} : > +42.5dBm
- P_{sat} : > +43dBm
- DCpower: 12V (nominal), 9-15V OK
- SMA-Female connectorized
- Typ. for Mobile Radio, HAM Radio, etc.

out (@ P_{sat}), under special (non-standard) warranty.

Photo



Description

HPA-820 is a 16Watt output (min. @ P_{3dB}) RF Power Amplifier; within frequencies of 760 to 880MHz; operating from a single 12VDC power supply (9-15VDC usable, but not recommended). With proper (active) cooling is capable of **20Watt RFpower**

Electrical Specifications @ +25°C, $Z_{in}=Z_{out}=50\Omega$, $V_{supply} = +12VDC$

IMPORTANT: MUST USE ACTIVE COOLING IF CASE TEMP. EXCEEDS 65°C or to ACHIEVE MAX. RFpower Output over 12W upto 20W (over +41dBm upto +43dBm), keeping under 18W recommended.

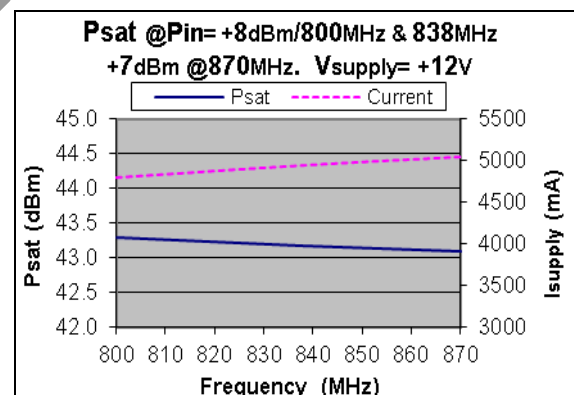
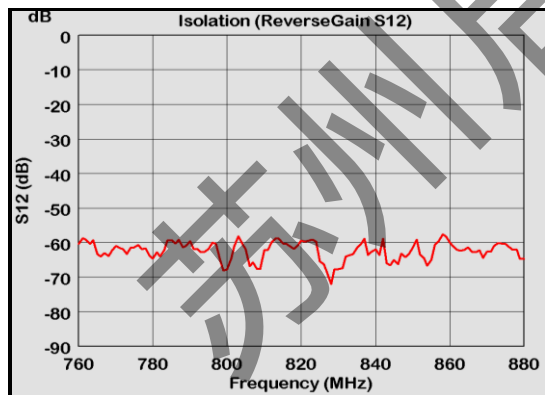
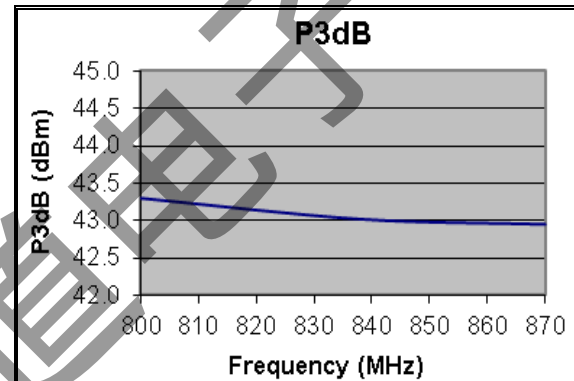
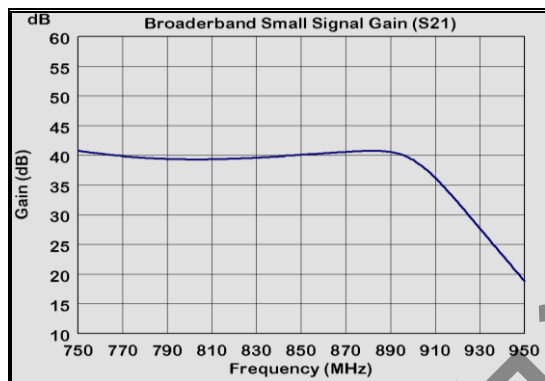
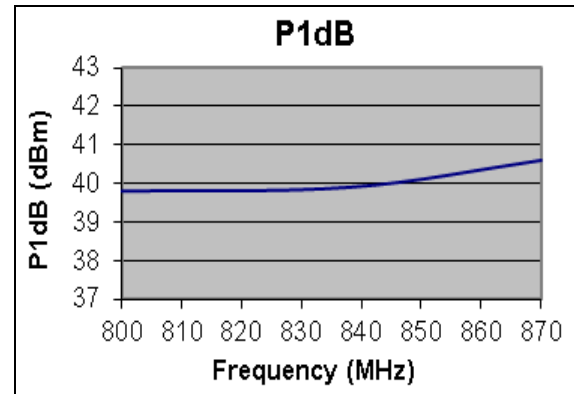
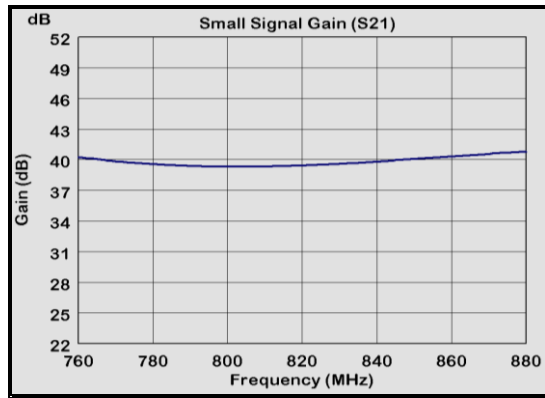
Parameter	Unit	Minimum	Typical	Maximum
Frequency Range	MHz	760		880
Small Signal Gain	dB	38.5	39.5	40.5
Output Power - 3dB gain compr. (P_{3dB})	dBm	+42.5	+43	
Output Power - saturated (P_{sat})	dBm	+43		
Reverse Isolation (S12)	dB		-65	-59
VSWR - Input (S11)	ratio:1	1.5 @880MHz	2.0 @820MHz	2.3 @760MHz
VSWR - Output (S22)	(unitless)	2.1 @830MHz	2.3	3.0 @760MHz
VSWR - Load Tolerance (non-destructive)	ratio:1			6
Efficiency @838MHz & P_{out} in dBm	%	<26 @ $P_{out}<+40$	33 @ $P_{out}+42$	36 @ $P_{out}+43$
DCpower Supply - voltage (unipolar, positive)	V	9 not recommended	12	15 not recommended
DCpower Supply - current: quiesc. (no RF)	A	1.3	1.5	
@ $P_{out} = +40dBm$	A		3.2	3.4
Size (incl. all hardware & heatsink [standard])	Inch	7.00 (L) x 3.25 (W) x 2.00 (H)		
Weight (incl. all hardware & heatsink [standard])	Oz	24		

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Typical Performance @ +25°C

(Power & S-parameters also available for download)

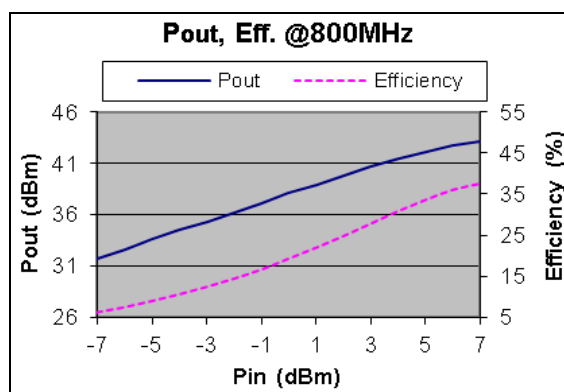
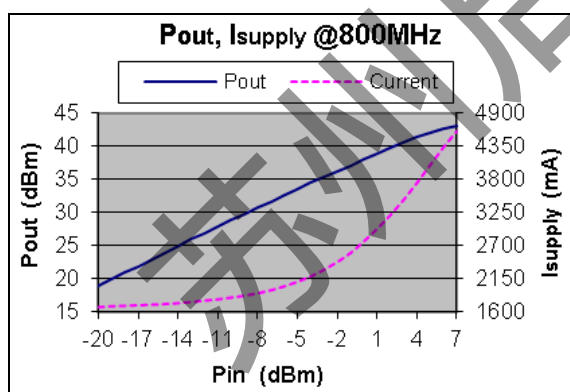
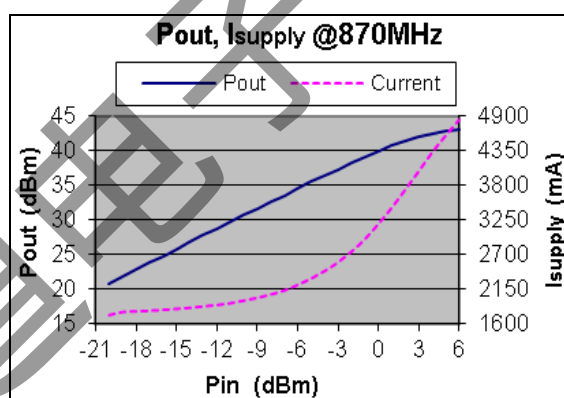
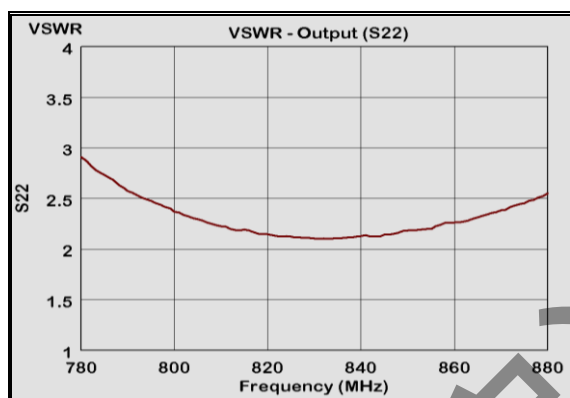
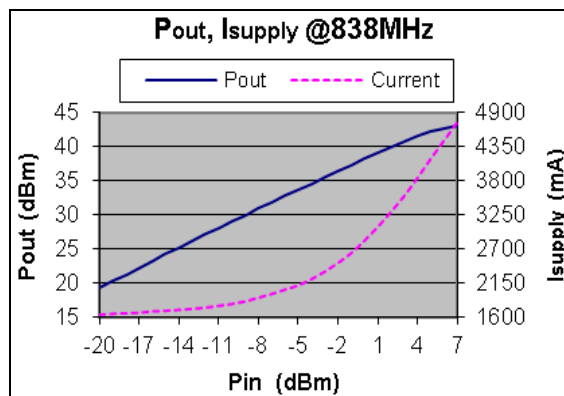
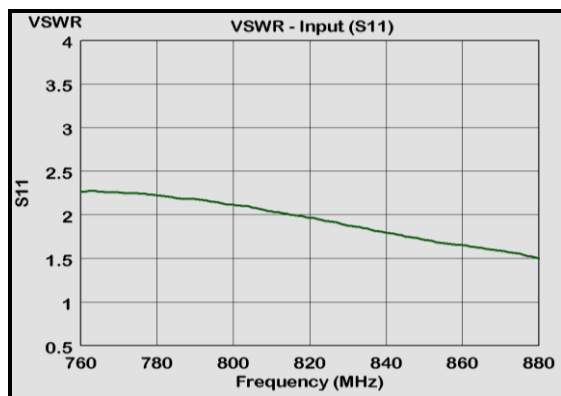


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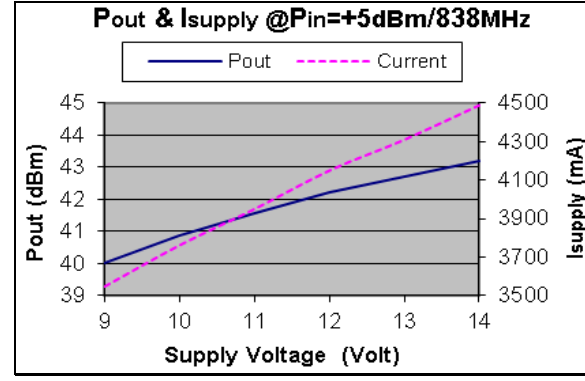
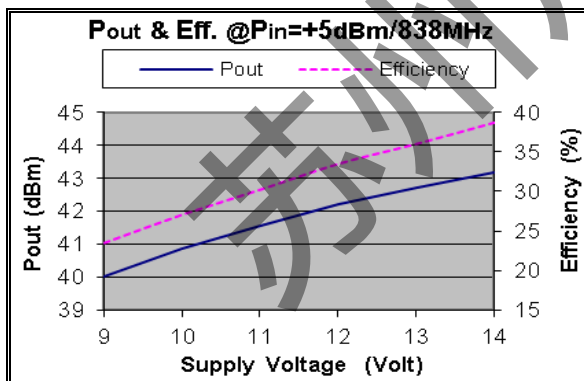
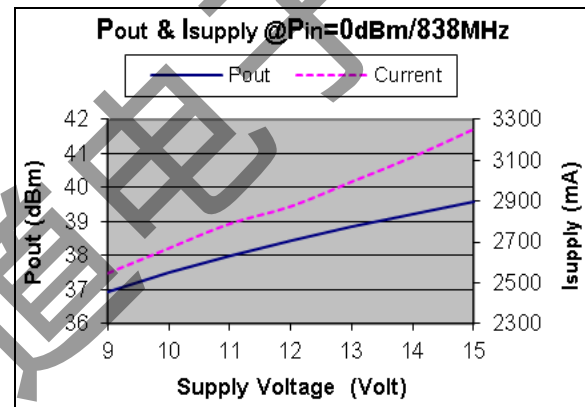
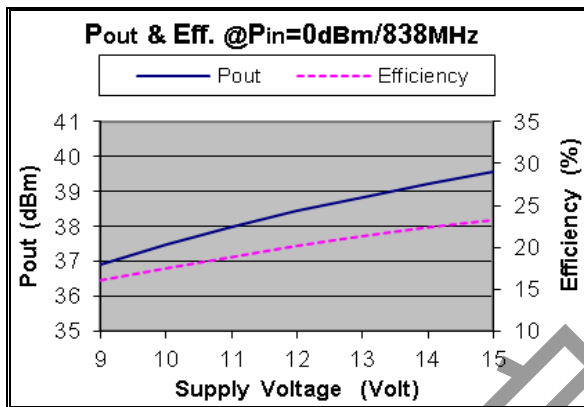
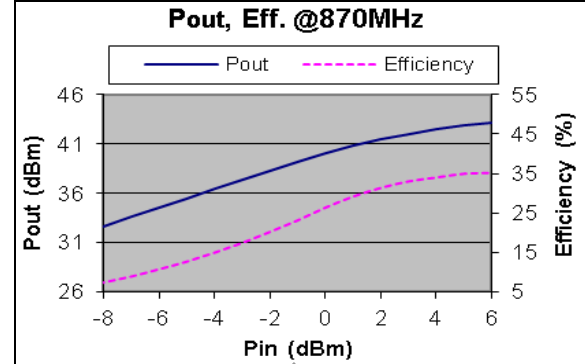
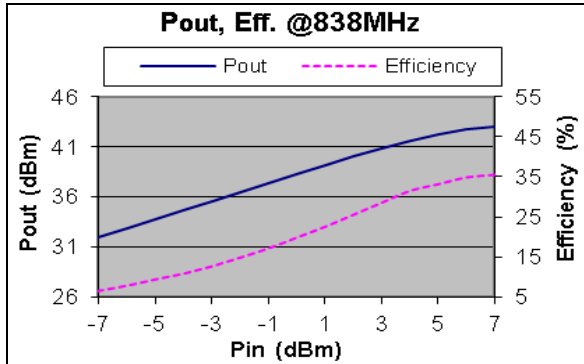
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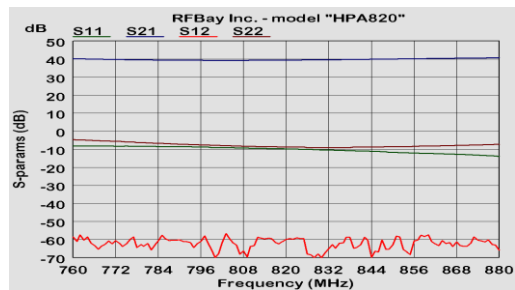


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Absolute Maximum Ratings

Parameter	Absolute Maximum
RF Input Power	+15dBm
Supply Voltage	+16V
Operating Temperature	-30 °C to +65 °C
Storage Temperature	-55 °C to +100 °C



The above parameters are independently guaranteed and are @Tcase <23°C, unless otherwise specified

APPLICATION NOTES (reliability):

• Thermal:

Specifications shown above as graphs, are at room temperature (23-25°C i.e. in a controlled environment), per international standard. If Amplifier's temperature is let rise significantly (e.g. towards max. 65-70°C) in customer's use, DCpower (supply) current may rise and stabilize at approx. 200-450mA higher values vs. shown in graphs, especially if at the same time RF PowerOut is driven beyond approx. 9Watt (contributing to selfheating, besides ambient temperature) - which is normal. Such increase in DCsupply current due to higher than standard ambient temperature, is less pronounced at low RF PowerOut; at below 1Watt it may add less than 90mA vs. current @25°C. Amplifier is designed to operate normal at **ANY** temperature or RF PowerOut within specs, this notice is only a recommendation to expect higher DCcurrent if user allows heat build-up far above standard 25°C.

Stock Heatsink is removable & upgradeable by the user, additionally Mountplate (opposite of heatsink) is strongly recommended to mount on a surface conducting heat away (e.g. mass of metal); some customers use active cooling such as fans (for extreme environment, even liquid cooling is an option), however be careful to not generate ElectroStatic Fields harmful for RF/Microwave devices. Use of inadequate Heatsink or HeatSpreader instead of stock, or inappropriate thermal-interface-material (TIM, i.e. grease, paste, semi-solids) voids warranty; *RF Bay Inc.* reserves the right to determine if a unit submitted for warranty service had been thermally abused. The key to reliability, is not only to minimize temperature rise, but also avoid repetitive thermal gradient (shock) due to cold-hot-cold cycling; these Amplifiers are meant for Commercial (rather than Mission-Critical) Mobile communications; in particular in Base & Fixed station applications with long-term continuous transmission and a higher On-Off frequency, please consider derating, redundancy system, maintenance schedule, or otherwise assure reliability.

• Oscillation & Load VSWR:

This amplifier's rugged design can withstand Load VSWR mismatch upto 6:1 (no degradation/destruction), guaranteed stable (no parasitic self-oscillation) for Pout<20Watt & Load VSWR under 3:1. If oscillation is observed, check if Load & Source impedances $Z_L = Z_s = 50 \text{ Ohm}$; adding DCpower decoupling ceramic + electrolytic capacitors (in parallel, closest possible to amplifier & minimal parasitic inductance to Ground) may help but not necessary, because already present internally.

• ESD:

Sensitive to ESD voltages to approx. 1KiloVolt - as typical for RF/Microwave amplifiers, appropriate ESD precaution is required.

• Mounting & DCpower connection:

Avoid excessive or torque (twisting) force onto DC terminals

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Outline (compact version)

Also available as a standalone higher-resolution 3D model (MCADsolid) & 2D drawing - see "Notes" on compact drawing (below):

